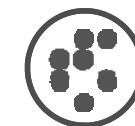
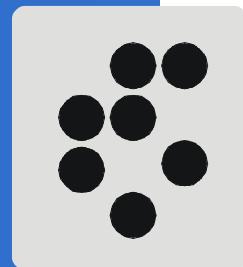


Uros Cvelbar

Jozef Stefan Institute, Slovenia

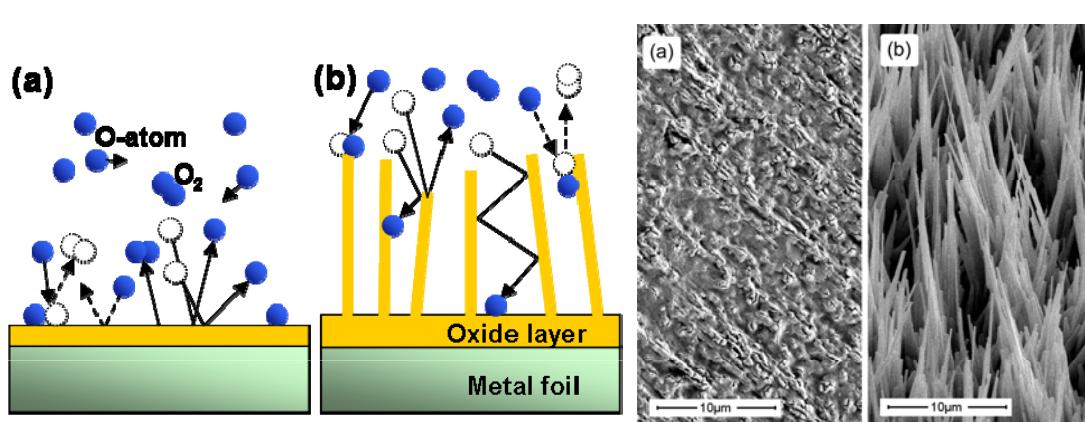
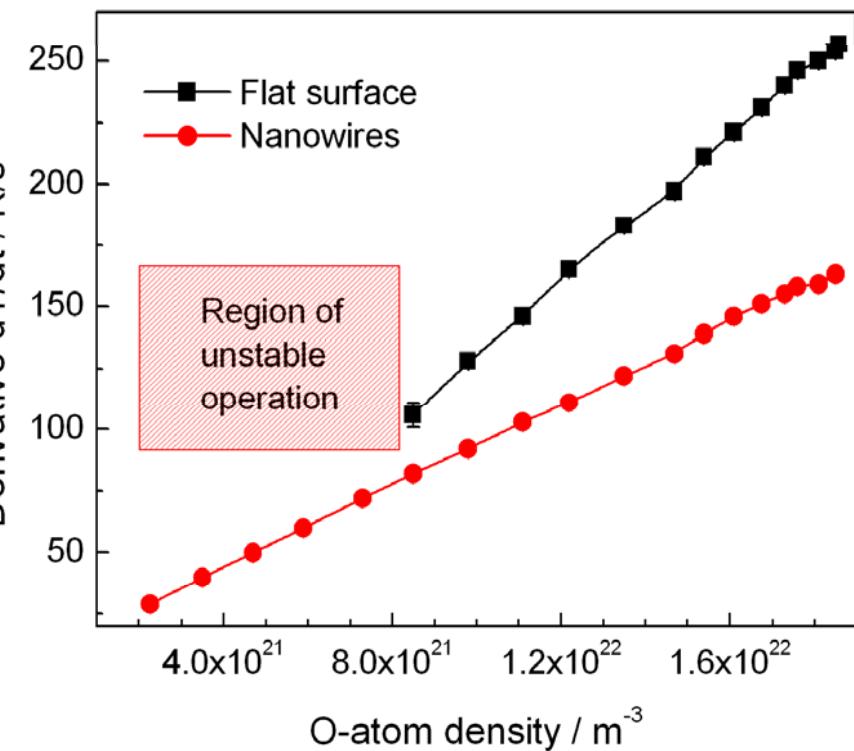
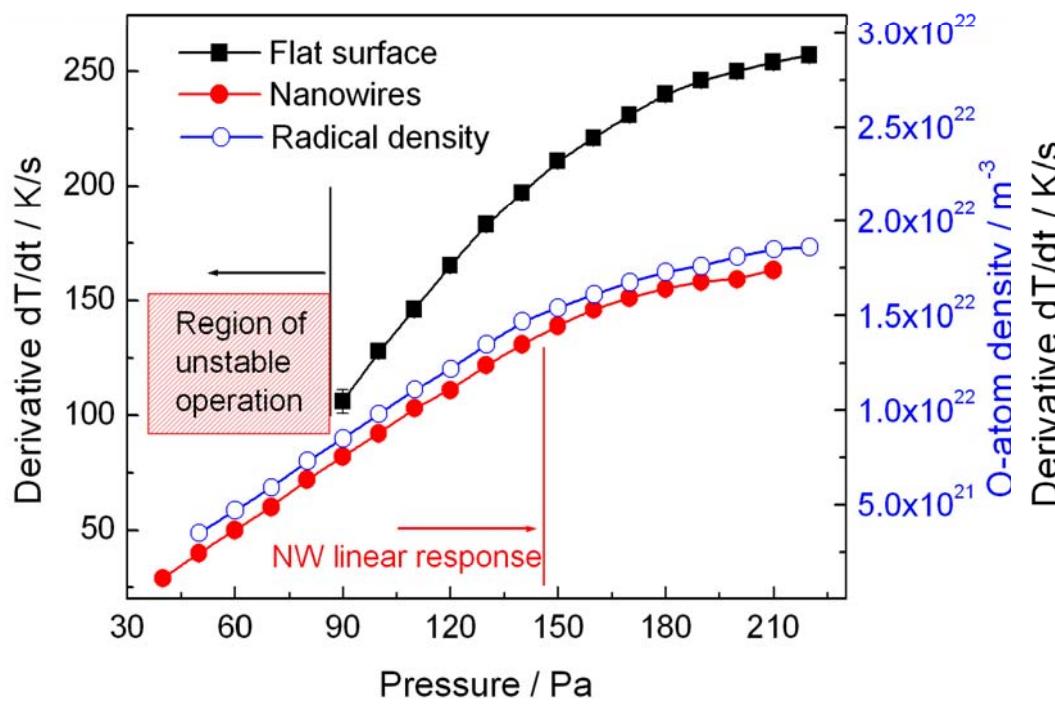
# Building new catalytic sensors and devices with plasma nanostructuring and large-scale synthesis of nanowires



PlasmaLab  
F4-IJS



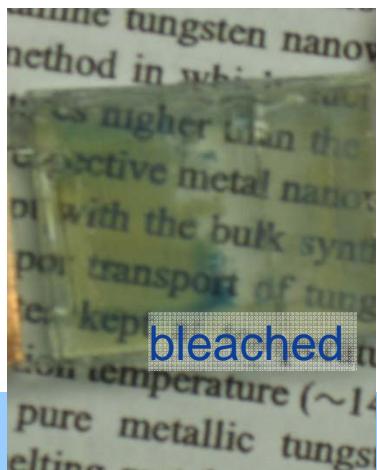
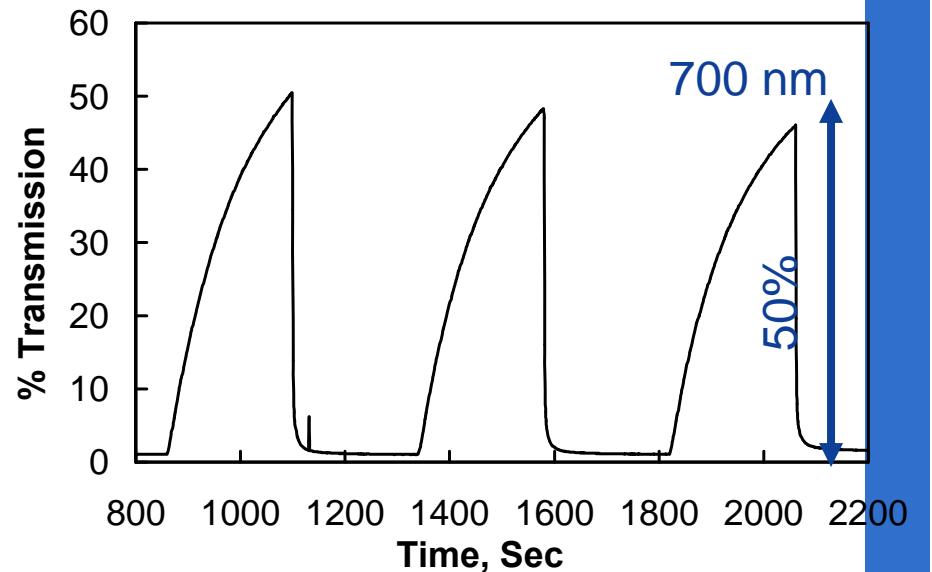
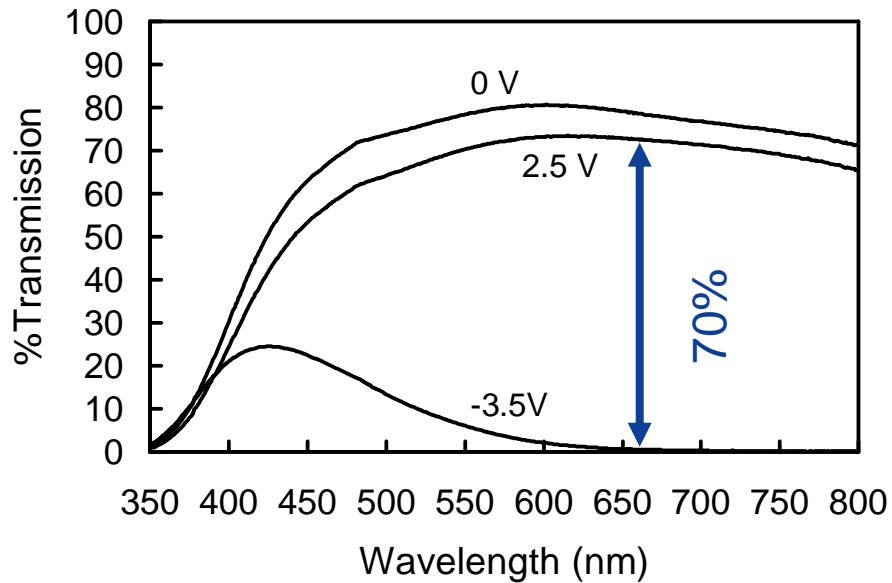
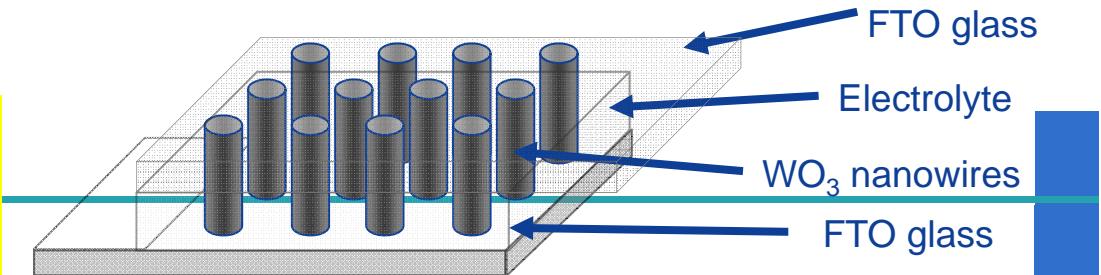
# Sensors - Measurements of neutrals with nanostructured surfaces



1. Linear response
2. Wider operation range
3. Better correlation with O-atom density

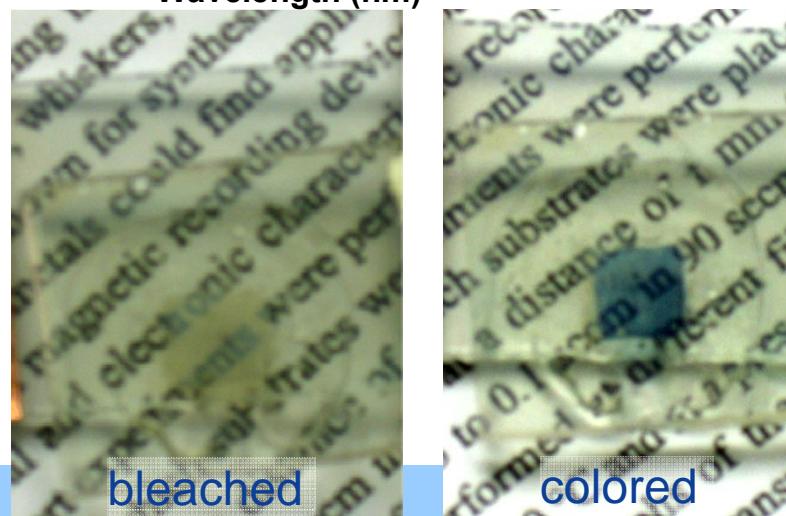
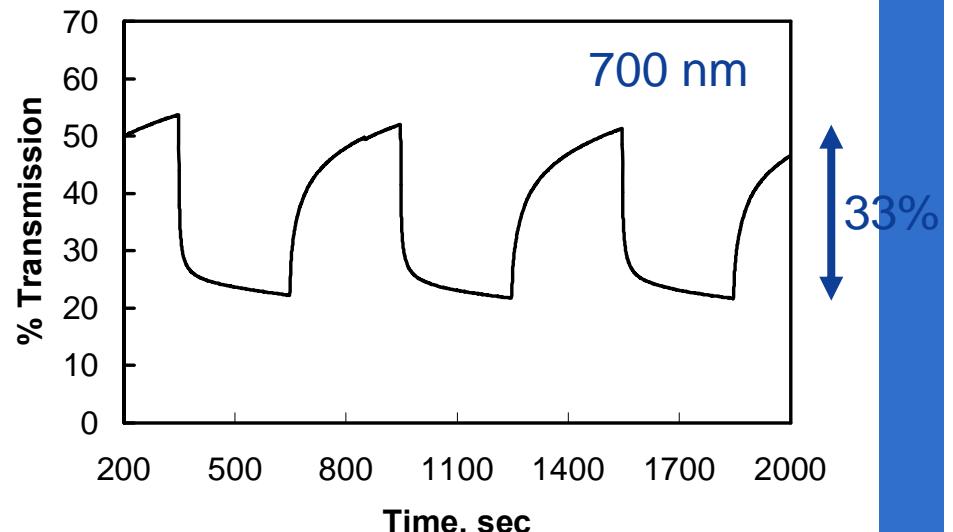
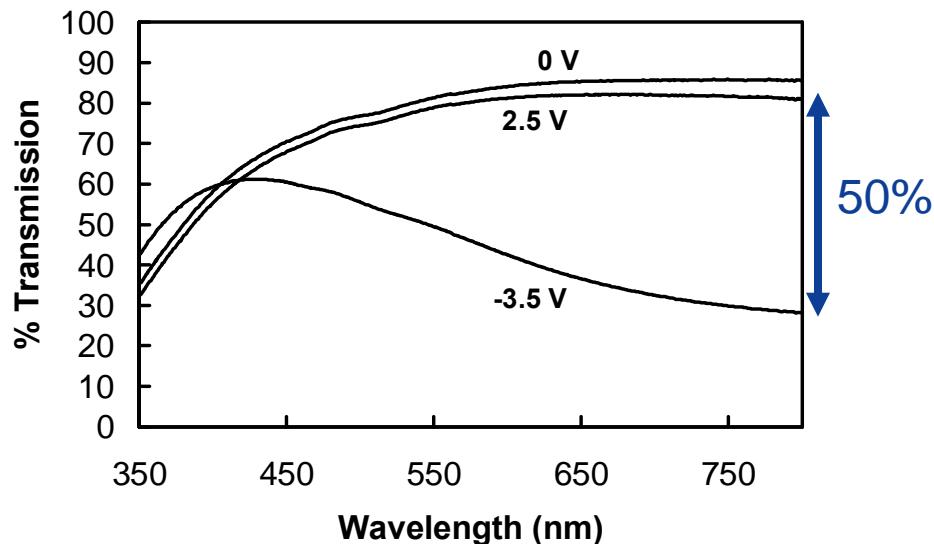
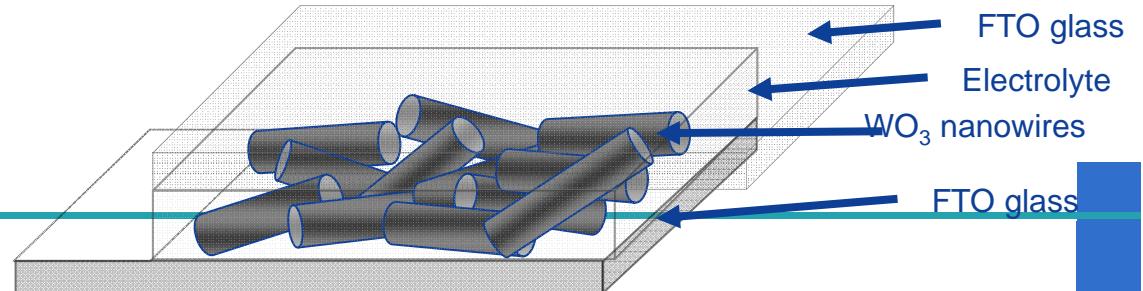
# Applications

Nanowire array electrodes for electrochromics



# Applications

Nanowire mat electrodes for electrochromics



Differences in the timescales of coloration and bleaching



## Problem to solve

**Synthesize large quantities of NW at small costs  
for satisfy future industrial needs!**

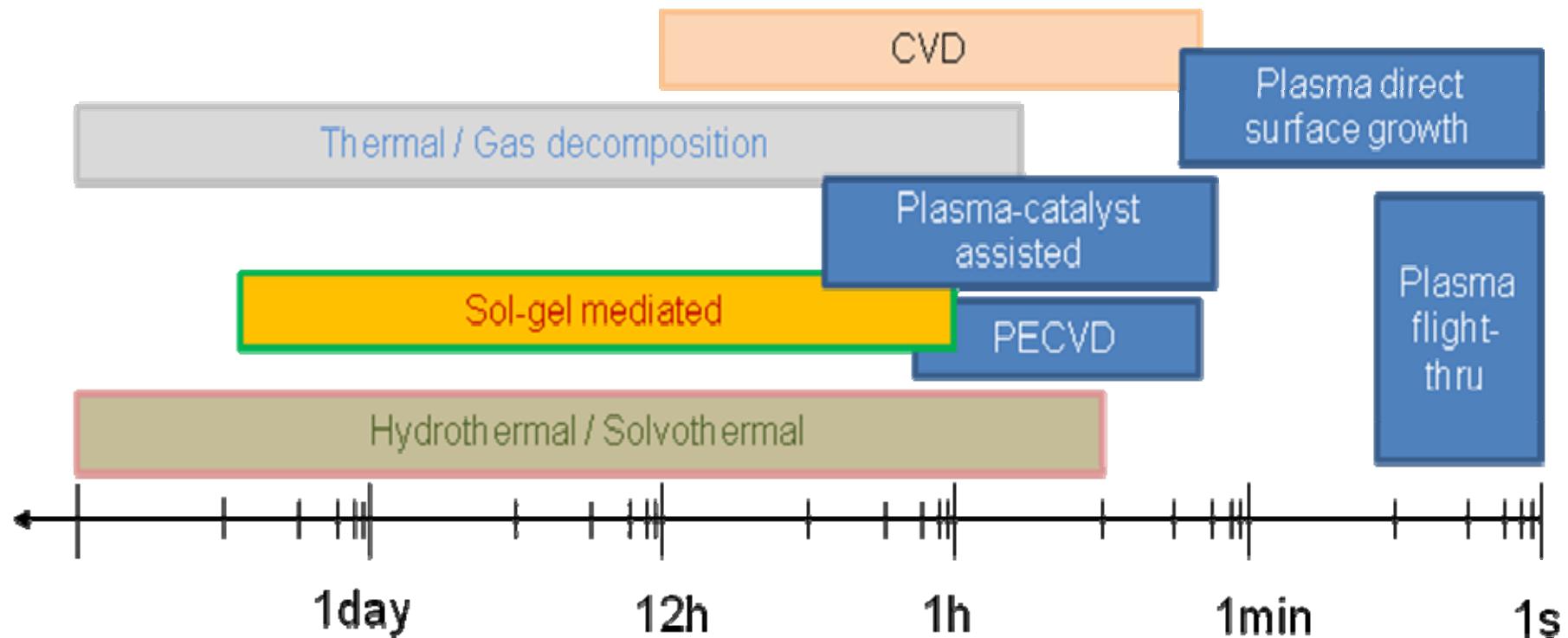
**Winner processes:**

1. Fast process
2. Cheap material in (powders) / out (NW)
3. Yield quantities
4. Efficient (and small) energy consumption
5. Pureness of material and new properties  
(crystallinity, p/n-type, etc.)
6. No post-processing, purification

**3D problem: TIME – QUANTITY- QUALITY**



# Time consumption for processing





# Plasma routes

Different plasma routes for nanostructuring and large – scale synthesis of nanowires

Separate NW –to build in

**1. Plasma-Enhanced Chemical Vapor Deposition (PECVD)**

**3. Plasma flight-thru**

Pre-deposited NW - electrodes

**2. Plasma-Catalyst assisted**

**4. Direct Plasma synthesis**

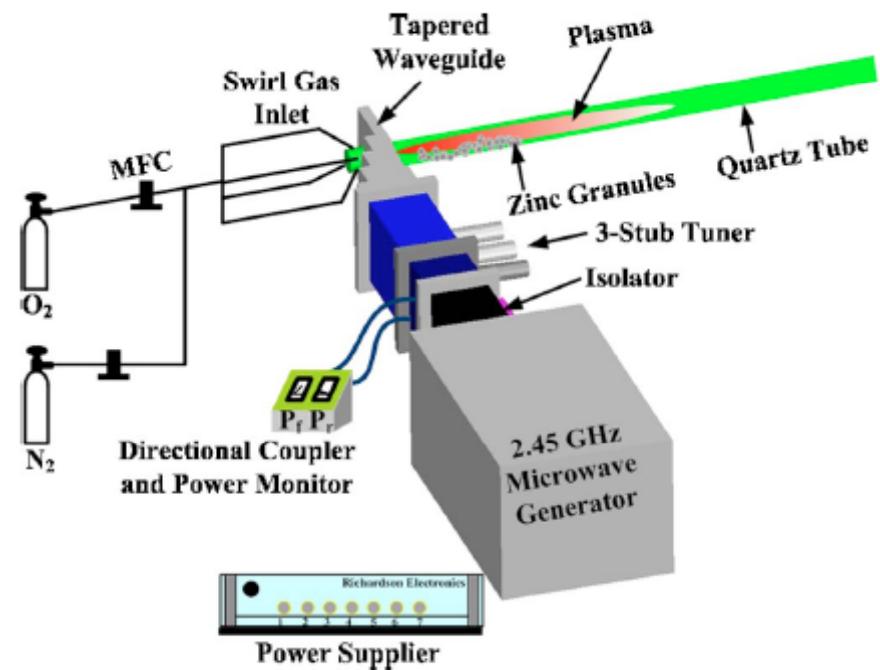
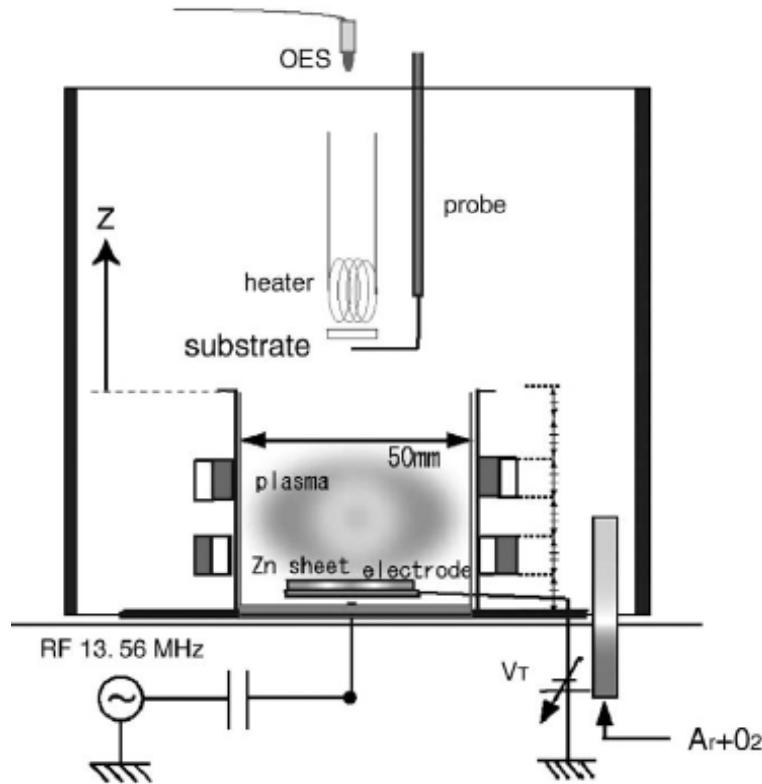
**5. Mixed plasma routes**

Case of **IRON OXIDE** and **ZINC OXIDE** – interest in sensors, solar cells, batteries or other photochemical and electrochromic applications



# 1. PECVD

Evaporation/melting-plasma interactions-deposition



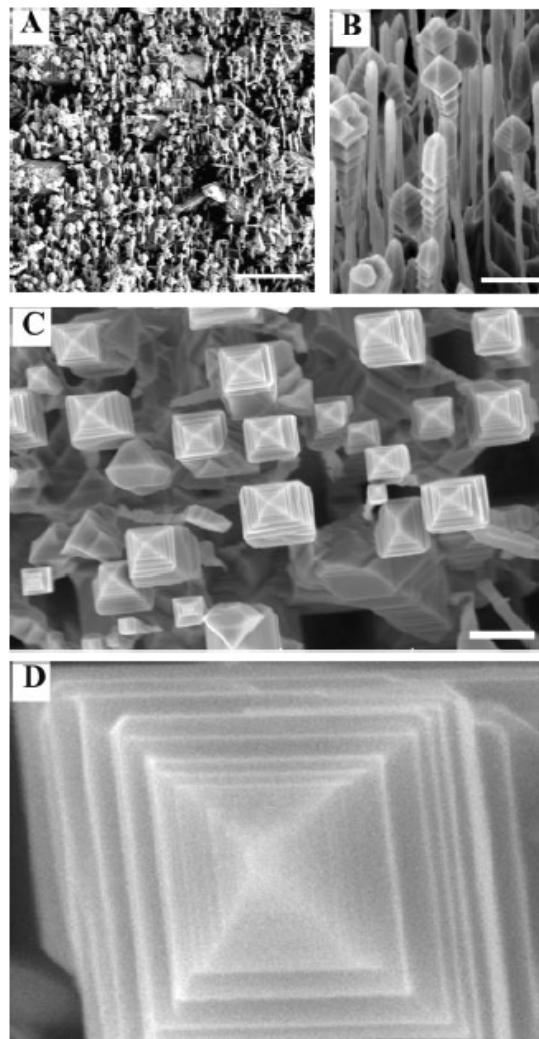
Liu et al. *Adv. Mater.* **2005**, 17, 1893-1897.  
Ostrikov et al. 2007 *Thin Solid Films* **516**, 6609-6615.  
Liu et al. 2003 *J. Appl. Phys.* **95**, 3141-3147.  
Kumeta et al. 2009 *Thin Solid Films* **518**, 3522-3525  
Ono H et al. 2009 *Thin Solid Films* **581**, 1016-1019  
Baxter et al. 2003 *Appl. Phys. Lett.* **83**, 3797-3799.

Hong et al. 2006 *Phys. Plasmas* **13**, 063506.  
Hong et al 2006 *Jpn. J. Appl. Phys.* **47**, 5940-5944.



## 1.PECVD

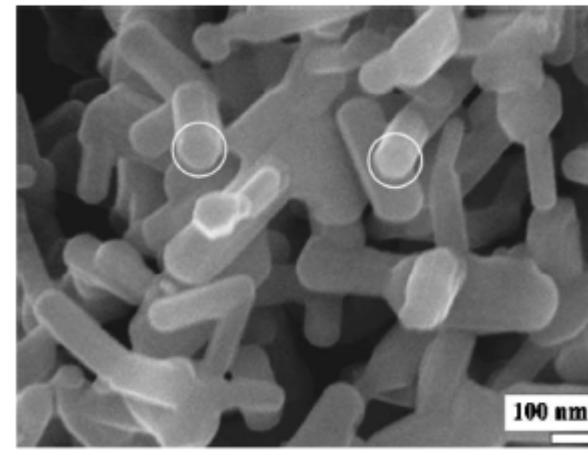
### Fe<sub>3</sub>O<sub>4</sub> NW



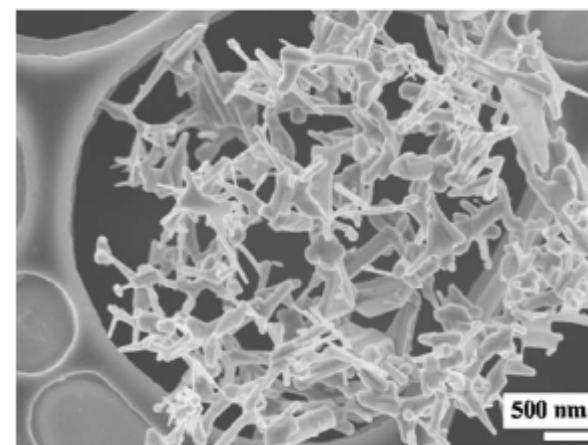
Liu et al 2005 Adv. Mater., 17, 1893-1897

Hong et al. 2006 Phys. Plasmas 13, 063506.

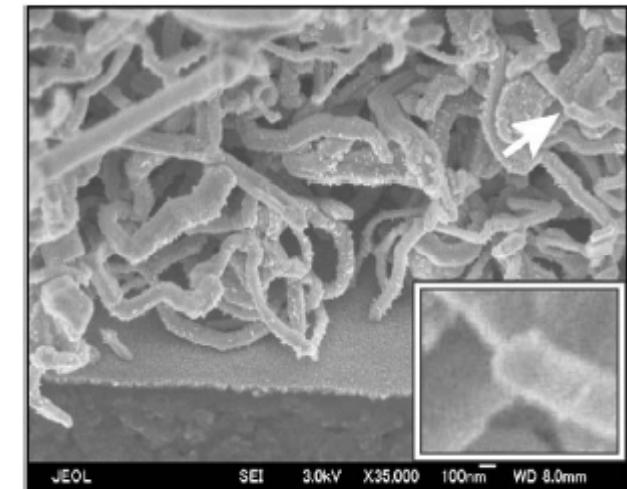
### ZnO NW



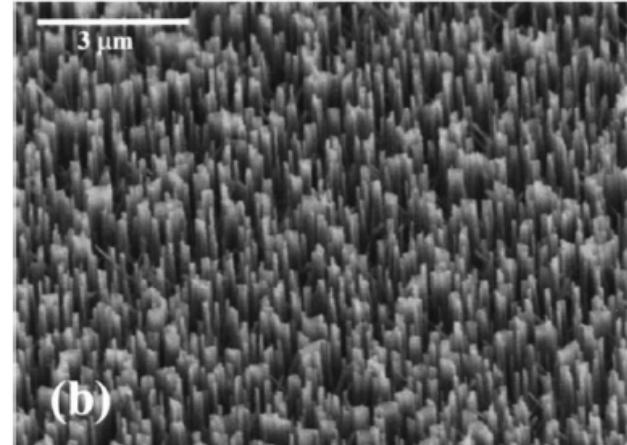
(a)



(b)



JEOL SEI 3.0kV X35,000 100nm WD 8.0mm



(b)

Ostrikov et al. 2007 Thin Solid Films 516, 6609-6615.

Liu et al. 2003 J. Appl. Phys. 95, 3141-3147.

Kumeta et al. 2009 Thin Solid Films 518, 3522-3525

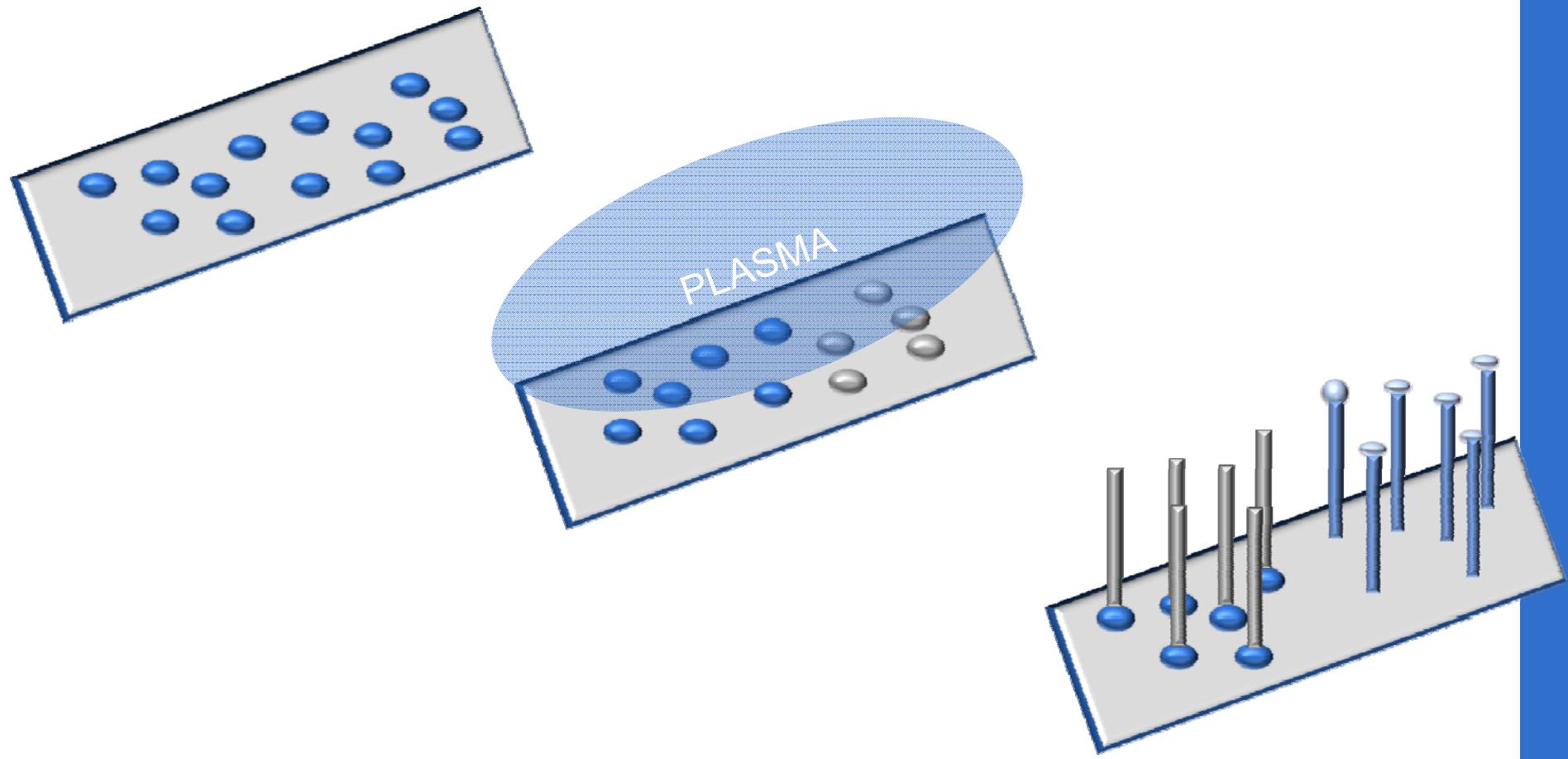
Ono H et al. 2009 Thin Solid Films 581, 1016-1019

Baxter et al. 2003 Appl. Phys. Lett. 83, 3797-3799.



## 2. Plasma-catalyst assisted

Catalyst deposition – plasma interactions – NW growth



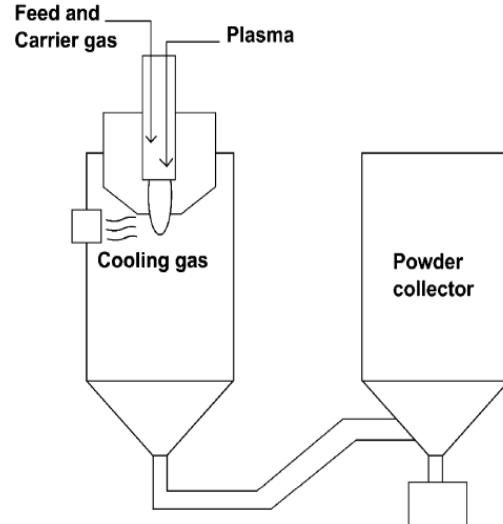
Fe<sub>2</sub>O<sub>3</sub> = O

ZnO = book *Inorganic nanowires and applications* by M. Meyyappan, MK Sunkara



### 3. Plasma flight-thru

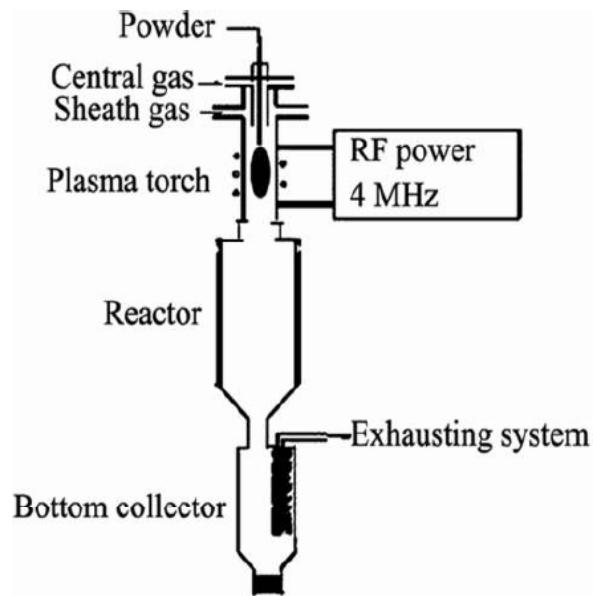
DC



Ko TS et al 2006 Mater. Sci. Eng. B 134, 54-58.

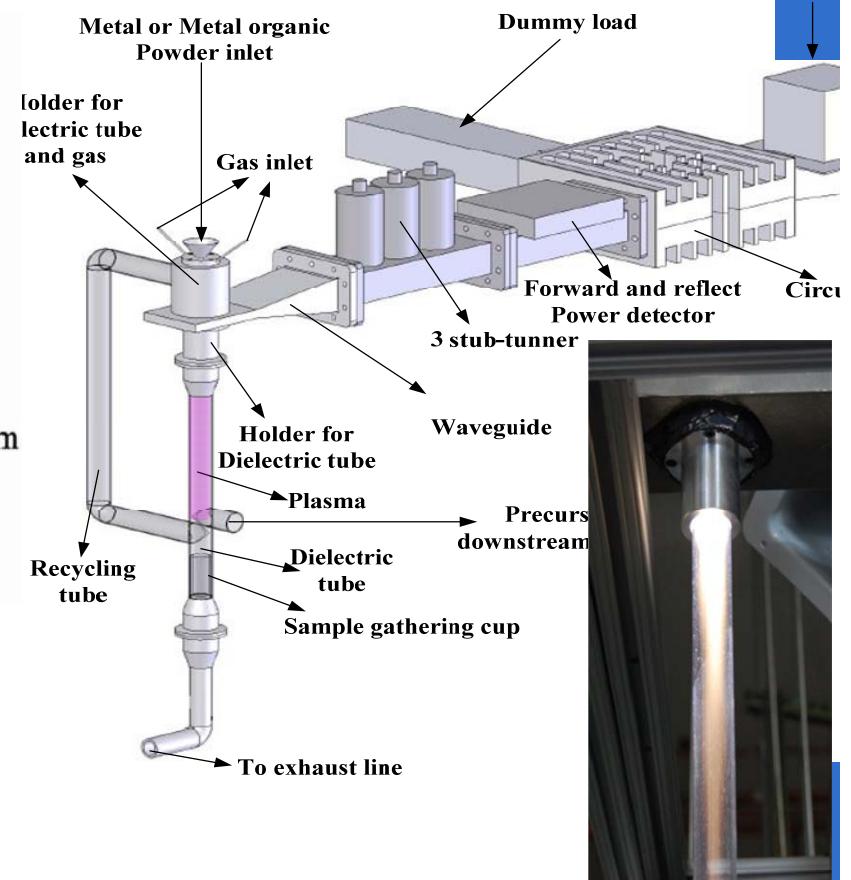
Lin Hf et al 2009 J. Cryst. Grow. 311, 1378-1384.

RF



Peng H et al 2007 J. Phys. Chem. C 111, 194-200.

MW



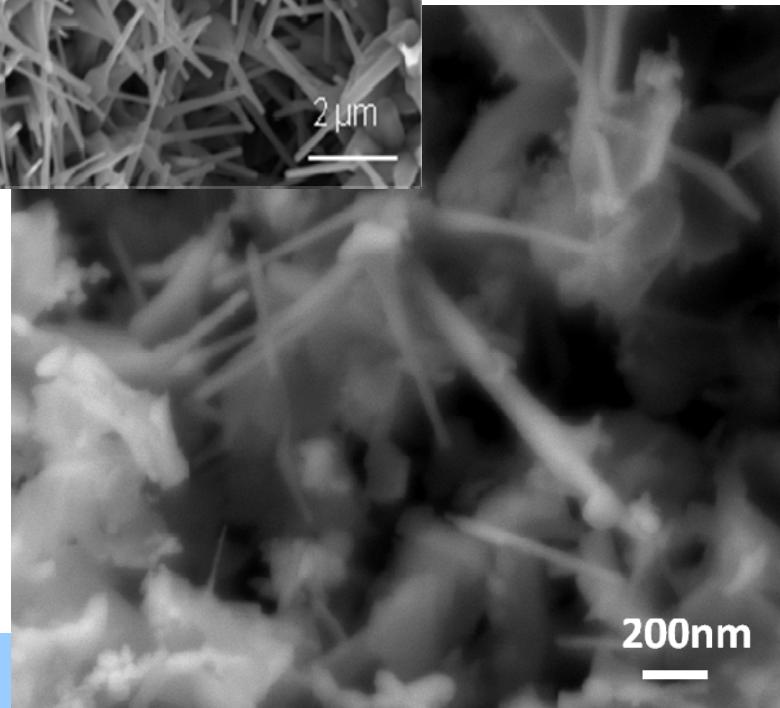
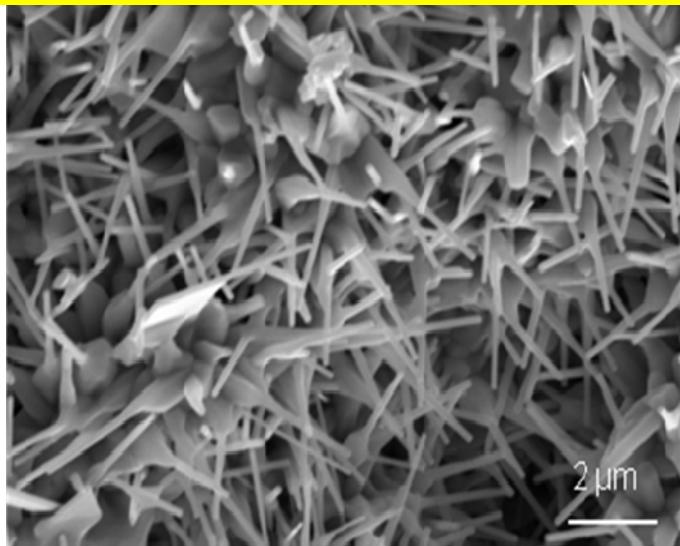
Kumar V et al 2008 J. Phys. Chem. C 112, 17750-17754.

Kim JH et al 2008 Informacije Midem 38, 237-243.



### 3. Plasma flight-thru

ZnO Nanowires



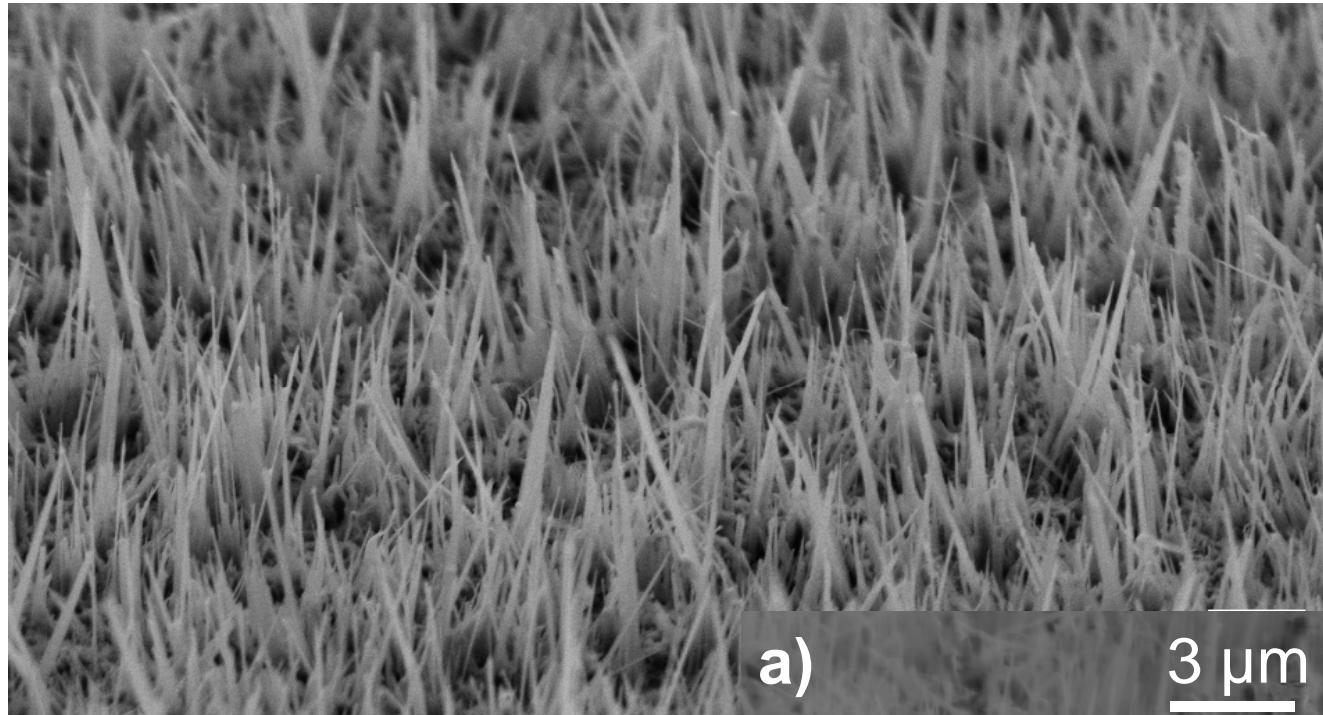
$\alpha$ Fe<sub>2</sub>O<sub>3</sub> Nanowires





## 4. Direct plasma growth

### $\alpha\text{Fe}_2\text{O}_3$ Nanowires

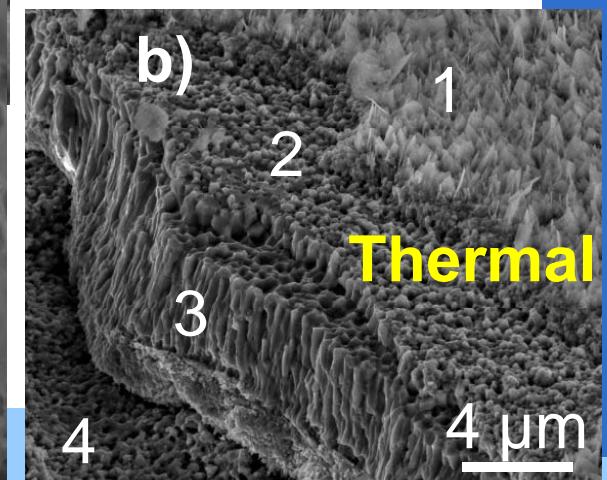
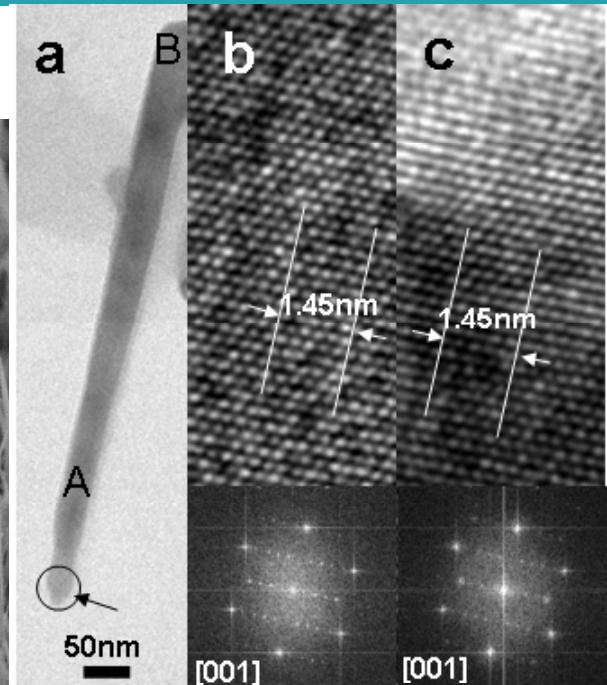
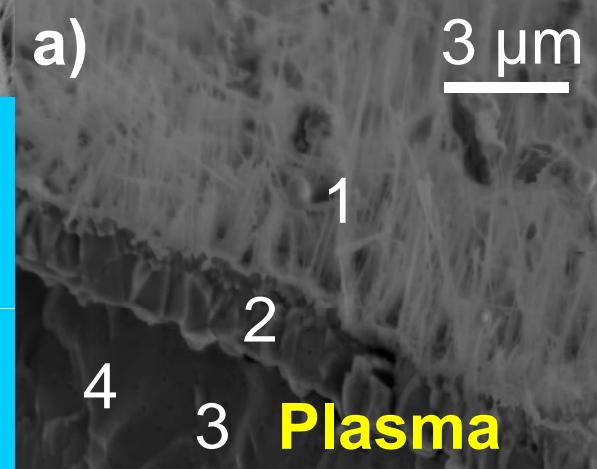


Chen, Cvelbar, Mozetic, Sunkara *Chem. Mater.* (2008) pp 00288y

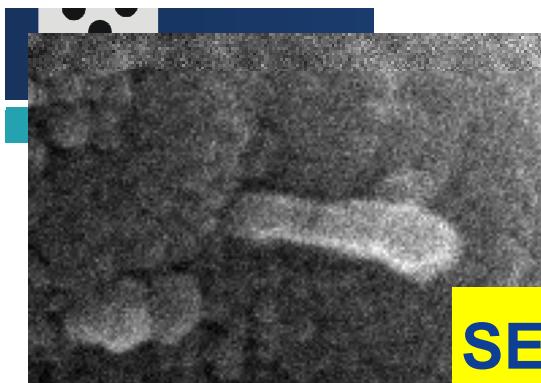
Cvelbar, Chen, Sunkara, Mozetic, 2008 *Small* 4, 1610-1614

Cvelbar U and Ostrikov K 2008 *Cryst. Growth Des.* 8, 4347-4349

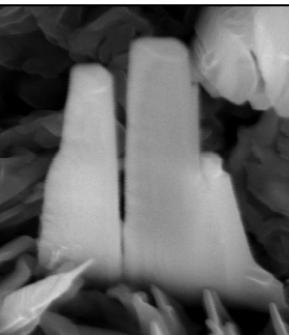
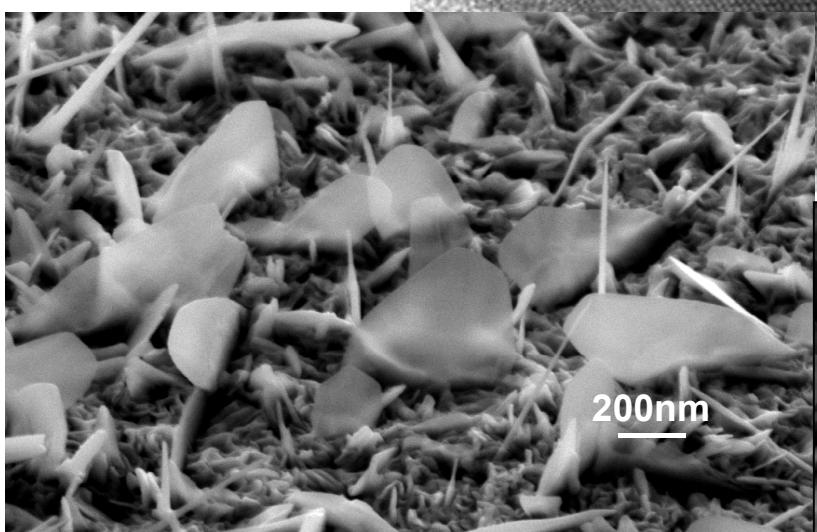
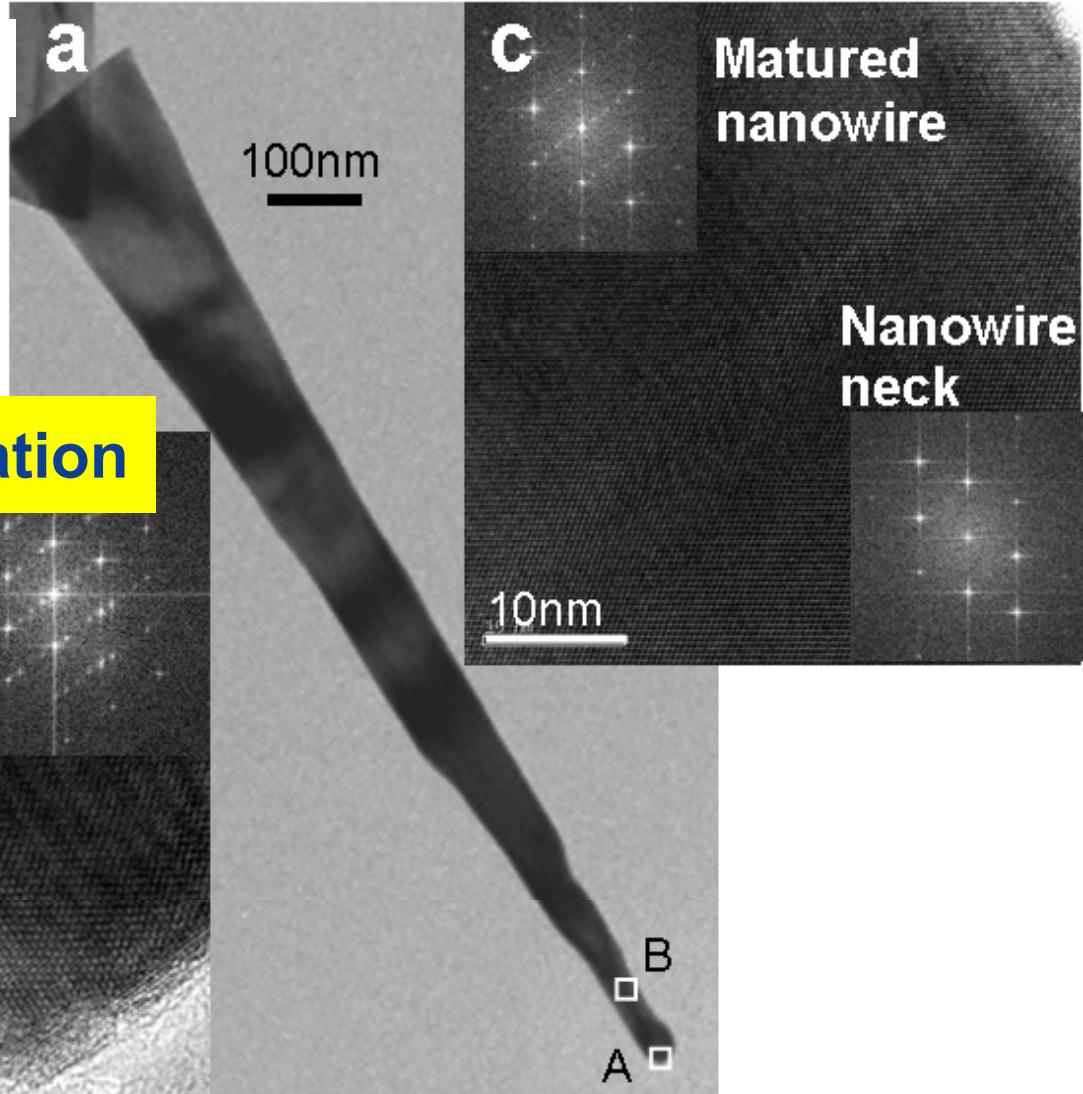
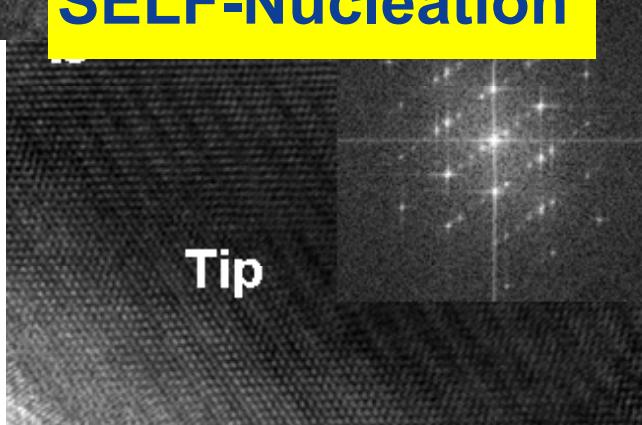
Ostrikov K, Levchenko I, Cvelbar U, Mozetic M and Sunkara MK 2010 *Nanoscale* 2, 2012-2027



#### 4. Direct plasma growth



**SELF-Nucleation**



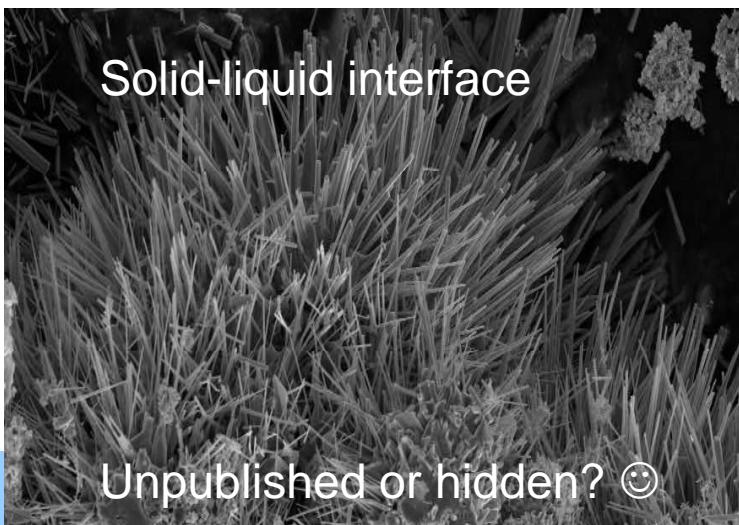


## 4. Direct plasma growth

### ZnO Nanowires

Sunkara

Solid-solid interface



Cvelbar

Solid-liquid interface

Unpublished or hidden? ☺



## 5. Mixed plasma routes

**Plasma-catalyst  
assisted + flight-thru**

**Plasma-catalyst  
assisted + flight-thru  
+ PECVD**

?

Iron oxides

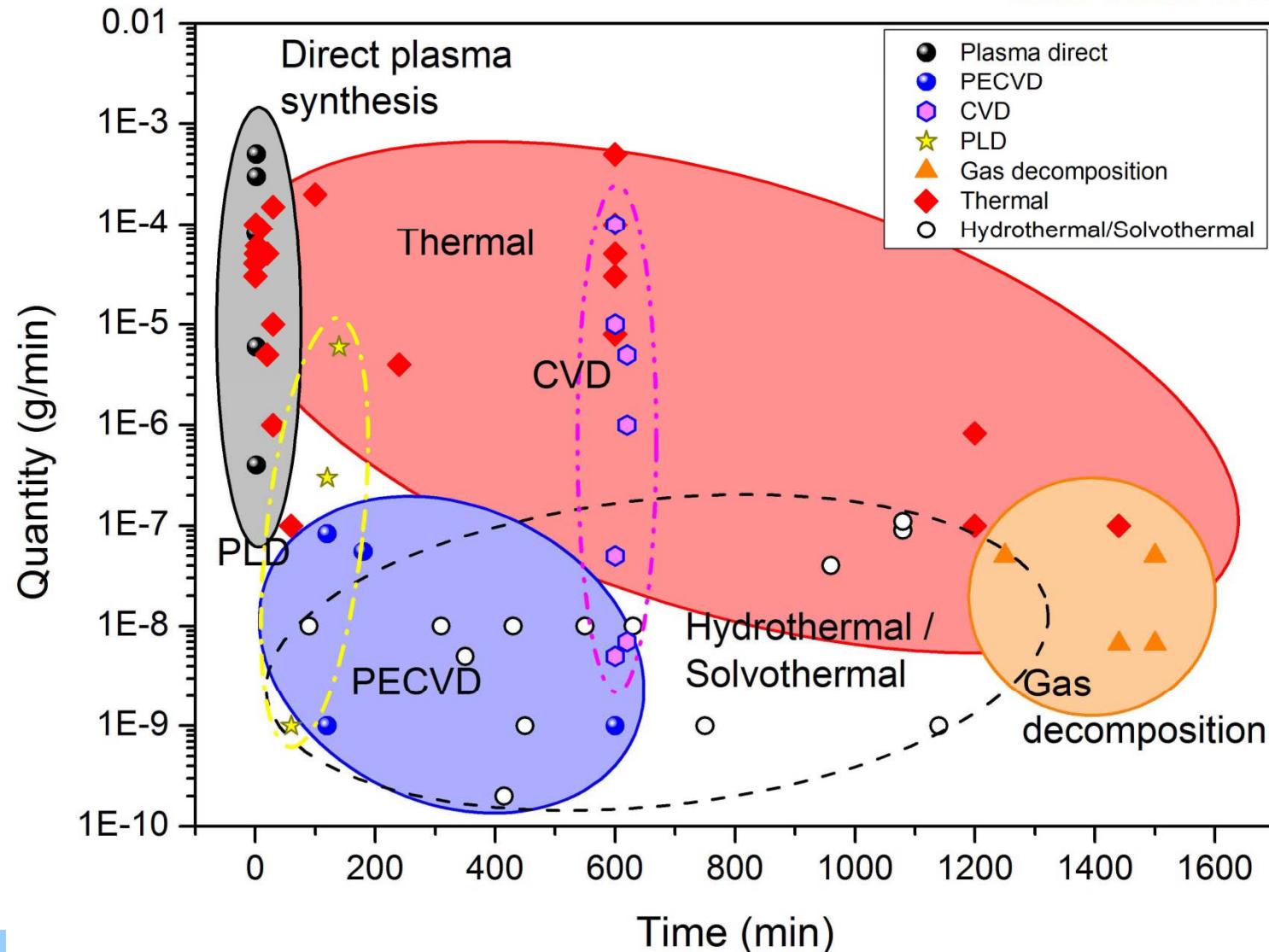
?

ZnO NW



# Time vs. Quantity (Fe oxide)

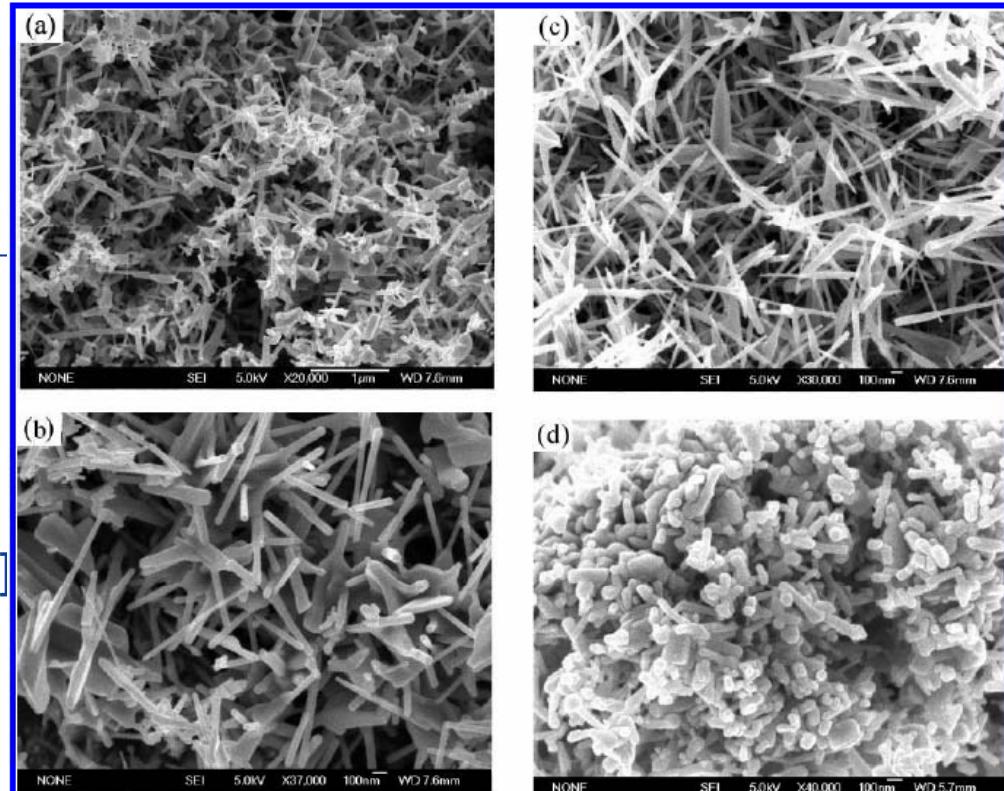
Iron Oxide NW





# Time vs. Quantity (ZnO)

1. PECVD  
 **$10^{-9} - 10^{-4}$  g/min**



## 3. Plasma flight-thru

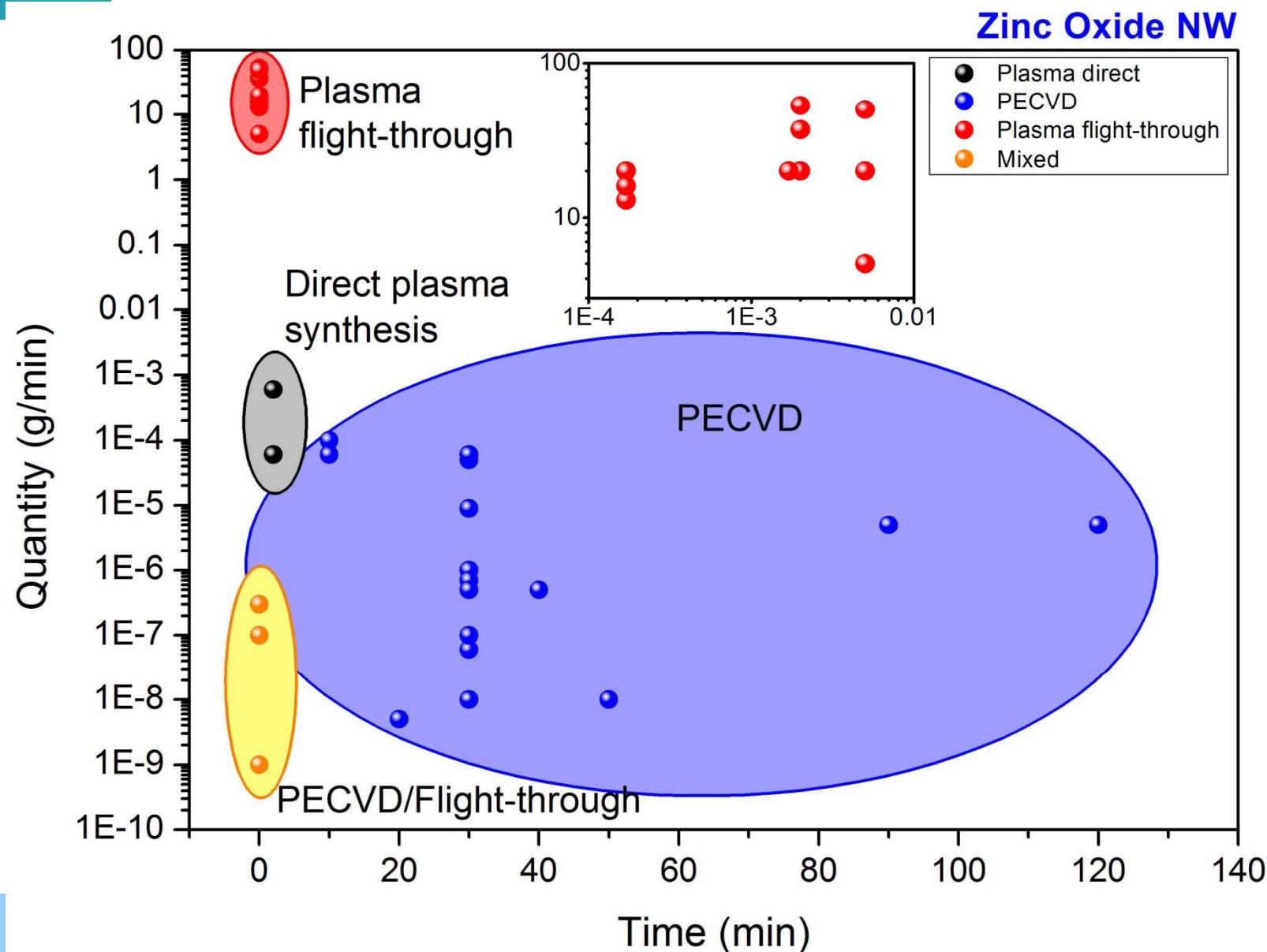
DC → **13 – 20 g/min**  
(Mat.Sci. Eng. B 134(2006))

RF → **20 g/min**, ratio I/d=14 [optimal]  
37 g/min, ratio I/d=8  
53 g/min, ratio I/d=2  
(J. Phys. Chem. C 111(2007))

MW → **5g/min**, ration I/d=20 (J.Phys.Chem C (2008))  
**<20g/min** (Midem Info 2008)



# Time vs. Quantity (Zn oxide)





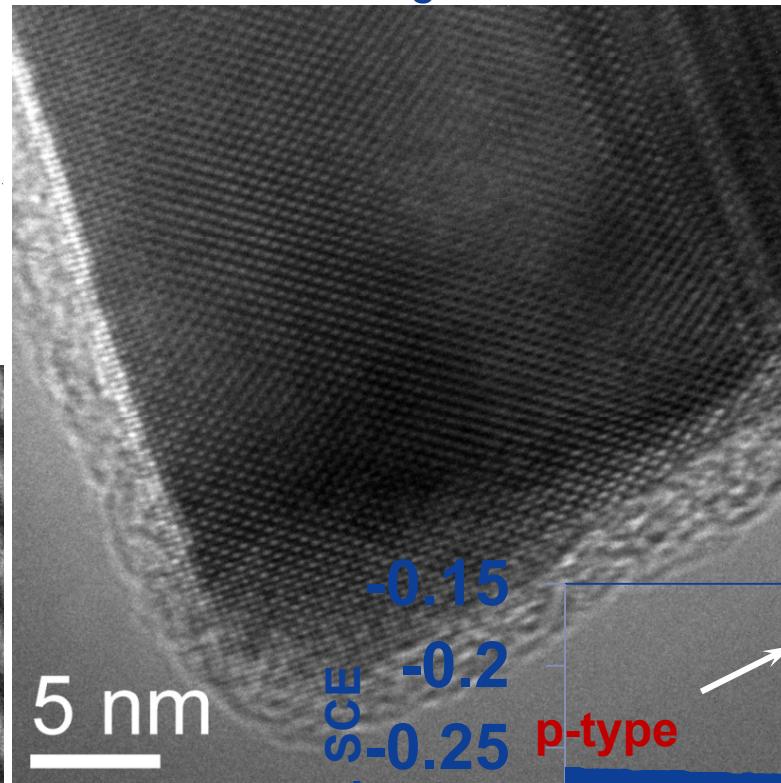
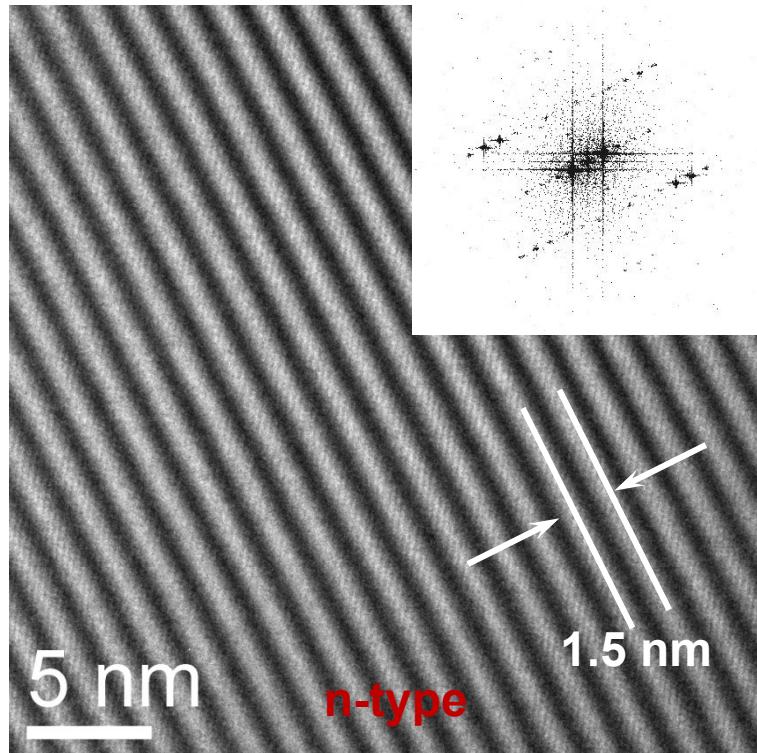
# Quality

- Advanced properties of NW
- “Pure” structures / no impurities (in most cases)
- Dimensions, shapes, ratio l/d
- Process control

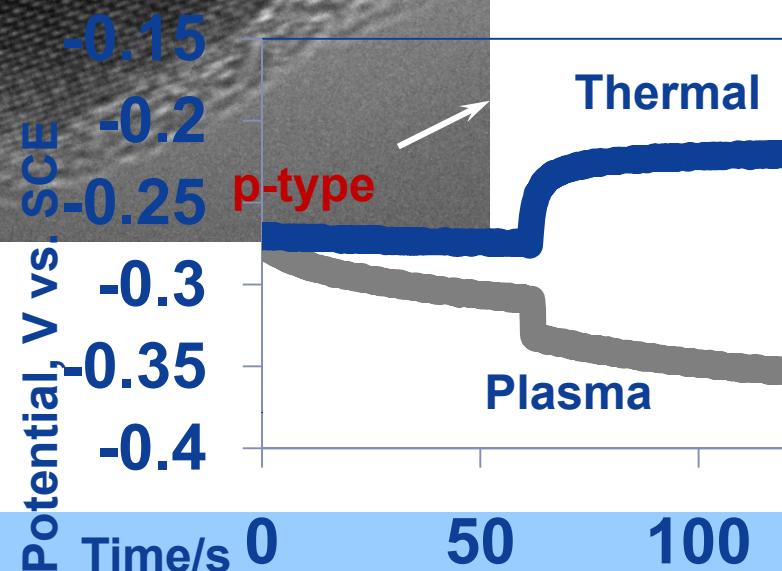


# Advantages of plasma nanostructures

Why is plasma so important for nanostructure or NW growth? - **SUPERSTRUCTURE**



Superstructured lattices (1/10 oxygen vacancies) grow only on plasma synthesized wires and not on thermal synthesized ones (furnace)!





# Prospectives & pros-cons

## 1. PECVD

1. Polycrystalline / crystalline NW
2. Aligned array growth is difficult to achieve
3. NW growth on substrate depends on the substrate
4. Multiple step procedures
5. Low energy efficiency per synthesized NW

## 2. Plasma –catalyst assisted

1. Impure NW
2. Multiple step procedures
3. High temperatures needed for dissolution of metal into catalyst for NW growth (e.g. 925C for Zn vapor dissolved into Au catalyst)
4. High energy consumption / low energy efficiency per synthesized NW
5. Growth limited by supplied catalyst

## 3. Plasma flight-thru

1. Single-crystalline NW
2. High amount of NW yield
3. Particles mixed with NW – post-purification needed
4. Difficult to control NW shape and ratio length/diameter
5. Difficult to control morphology
6. Synthesis smaller than second
7. Influence of reactor size to feed and efficiency of conversion/synthesis
8. Single-step procedure
9. Good energy efficiency per synthesized NW

## 4. Direct plasma synthesis

1. Single-crystalline NW
2. Medium amount of NW yield
3. No purification needed
4. Good control of NW shape and ratio length/diameter
5. Difficult to control nucleation
6. Nucleation determines the number of NW
7. Difficult to control alignment of NW
8. Synthesis in order of seconds to minutes
9. Single-step procedure
10. Medium energy efficiency per synthesized NW